NSN 5961-01-429-6309

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-429-6309 **Inclosure Material:** Glass **Overall Length:** 0.450 inches **Overall Diameter:** 0.092 inches **End Application:** Pacer dawn **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 regulator voltage, dc and 8.6 reverse voltage, peak **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak and 250.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No